



Bidirectional Transil™ array for data line protection

SO-8

Functional diagram

Features

- High surge capability Transil array: $I_{PP} = 40 \text{ A} (8/20 \mu \text{s})$
- Peak pulse power: 300 W (8/20 µs)
- Up to 5 bidirectional Transil functions
- Low clamping factor (V_{CL} / V_{BR}) at high current level
- Low leakage current
- ESD protection up to 15 kV

Complies with the following standards

- MIL STD 883G- Method 3015-7: class 3B
 - 25 kV (human body model)

8 GND I/O1 ■ IEC 61000-4-2 level 4 7 1/02 - 15 kV (air discharge) 6 I/O3 - 8 kV (contact discharge) **I/O4** 5 GND

Figure 1.

Applications

Differential data transmission line protection, such

- RS-232
- RS-423
- RS-422
- RS-485

Description

Transil diode arrays provide high overvoltage protection by clamping action. Their instantaneous response to transient overvoltages makes them particularly suited to protect voltage sensitive devices such as MOS technology and low voltage supplied IC's.

The ITA series combines high surge capability against energetic pulses with high voltage performance against ESD.

TM: Transil is a trademark of STMicroelectronics

Characteristics ITAxxB1

1 Characteristics

Table 1. Absolute ratings $(T_{amb} = 25 \, ^{\circ}C)$

Symbol	Parameter	Value	Unit	
P _{PP}	Peak pulse power $(8/20 \mu s)^{(1)}$ T_j initial = T_{amb}		300	W
I _{PP}	Peak pulse current $(8/20 \ \mu s)^{(1)}$ T_j initial = T_{amb}		40	Α
I ² t	Wire I ² t value ⁽¹⁾	0.6	A ² s	
T _j	Maximum operating junction temperature	125	°C	
T _{stg}	Storage temperature range	-55 to +150	°C	
T _L	Maximum lead temperature for soldering during 10 s at 5	260	°C	

^{1.} For surges greater than the specified maximum value, the I/O will first present a short-circuit and after an open circuit caused by the wire melting.

Table 2. Electrical characteristics ($T_{amb} = 25$ °C)

Symbol		F	Paramete	r					Į	la-	
V_{RM}	Stand-off voltage								IPP		
V_{BR}	Breakdown voltage										
V_{CL}	Clamping voltage				IRM V					.,	
I _{RM}	Leakage current								٧	RM VCL VBR	V
I _{PP}	Peak pulse current										
αΤ	Voltage temperature coefficient										
С	Capacit	ance					'				
	ı	V _{BR}	@ I _R	I _{RM} @	V _{RM}	V _{CL}	@ I _{PP}	V _{CL}	@ I _{PP}	αΤ	С
Order	code	min.					8/20 µs	max.	8/20 μs	max.	max.
Order code		(1)		max.		(1)		(1)			(2)
		V	mA	μΑ	V	V	Α	V	Α	10 ⁻⁴ / °C	pF
ITA6V	′5B1	6.5	1	10	5	10	10	12	25	4	750
ITA10)B1	10	1	4	8	15	10	19	25	8	570
ITA18	3B1	18	1	4	15	25	10	28	25	9	350
ITA25B1		25	1	4	24	33	10	38	25	12	300

^{1.} Betwenn I/O pin and ground.

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^{2.} Between two input pins at 0 V Bias, F = 1 MHz.

ITAxxB1 Characteristics

Figure 2. Pulse waveform

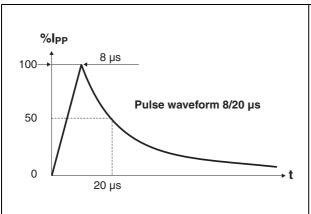


Figure 3. Typical peak pulse power versus exponential pulse duration

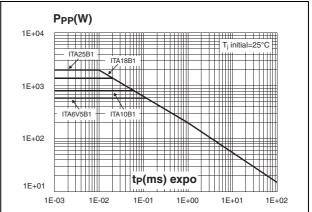
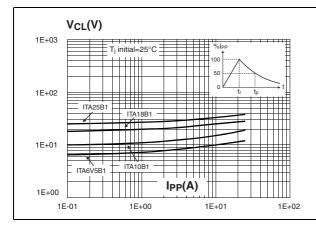


Figure 4. Clamping voltage versus peak pulse current (exponential waveform 8/20 µs)

Figure 5. Peak current I_{DC} inducing open circuit of the wire for one input/output versus pulse duration (typical values)



1E+02

1E+02

1E+00

1E+02

1E+00

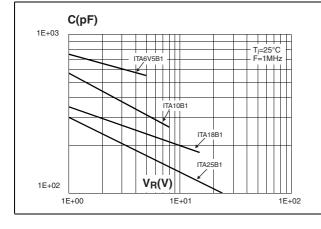
1E+00

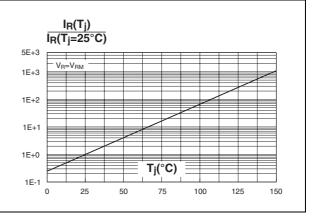
1E+00

1E+01

Figure 6. Junction capacitance versus reverse applied voltage for one input/output (typical values)

Figure 7. Relative variation of leakage current versus junction temperature





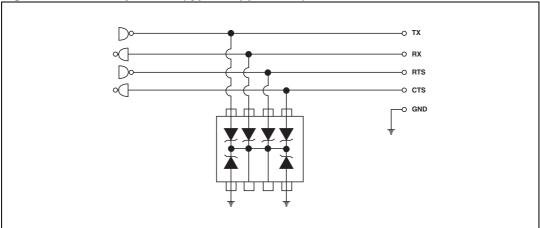
2 Application information

This monolithic Transil Array is based on 6 unidirectional Transils with a common cathode and can be configurated to offer up to 5 bidirectional functions. This imposes a maximum differential voltage between 2 input pins (see *Table 3*).

Table 3. Maximum differential voltages

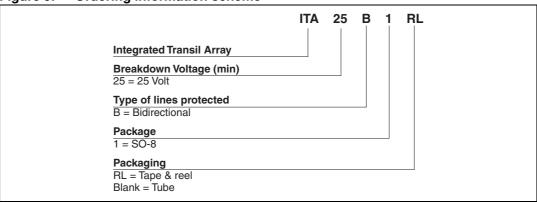
Order code	Maximum differential voltage between two input pins at 25 °C
ITA6V5B1	± 3.5 V
ITA10B1	± 5.0 V
ITA18B1	± 9.0 V
ITA25B1	± 12.5 V

Figure 8. RS-232 junction (typical application)



3 Ordering information scheme

Figure 9. Ordering information scheme



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ITAxxB1 Package information

4 Package information

Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 4. SO-8 dimensions

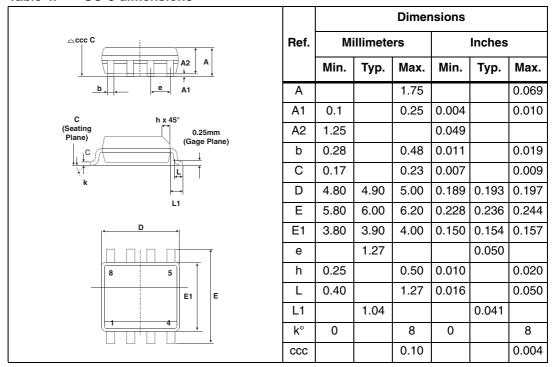
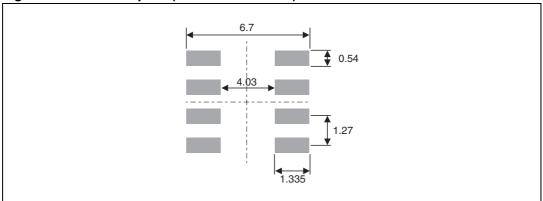


Figure 10. SO-8 footprint (dimensions in mm)



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Ordering Information ITAxxB1

5 Ordering Information

 Table 5.
 Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
ITA6V5B1	6V5B1			2000	Ammopack
ITA6V5B1RL	6V5B1			2500	Tape and reel
ITA10B1	10B1			2000	Ammopack
ITA18B1	18B1	SO-8	0.08 g	2000	Ammopack
ITA18B1RL	18B1			2500	Tape and reel
ITA25B1	25B1			2000	Ammopack
ITA25B1RL	25B1			2500	Tape and reel

6 Revision history

Table 6. Document revision history

Date	Revision	Description of changes
13-Dec-2004	1	First issue.
15-Nov-2007	2	Reformatted to current standards. SO-8 package dimensions update. Updated pulse waveform parameters in <i>Figure 2</i> .

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